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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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EMI Suppression Beads (2643250202)



Part Nu	mber: 2	264325020	2		
43 SHII	ELD B	EAD			
□ Digits □ 3&4 = □ last di □ Beads "2" as t □ Upon	s 1&2 = = mater igit 1= s with a he last reques	"1" as the digit. t beads can	ass, nd ed, 2 = burnished a last digit of the par	rt number are not bar Parylene coating.	oated. burnished. Parts that are burnished to break the sharp edges have a The last digit of the Parylene coated part is a "4". The minimum
Fair- Ri	te offer	rs a broad s	election of ferrite I	EMI suppression b	eads with guaranteed minimum impedance specifications.
□Our "	Shield	Bead Kit" (part number 01990	000019) contains a	selection of these beads.
□For aı	ny EMI	suppression	on bead requiremen	nt not listed here, for	eel free to contact our customer service for availability and pricing.
		ŕ	ne bead length, can	be modified to sui	t specific applications.
Weight		T T		- I	_
	mm	mm tol	nominal inch	inch misc.	
A	6.35	± 0.15			
		 	0.25	_	
В	2.95	+0.45	0.25	_	
В		 	+		Chart Legend
B C + Test • The c	2.95 25.4 frequent column dc H fid impeda	+0.45 ±0.75 acy "H (Oe)" geld in the apartice of the	0.125 1 ives for each bead pplication is this va	alue of "H" times t	Chart Legend bias field in oersted for 1 turn and 1 ampere direct current. The the actual NI (ampere- turn) product. For the effect of the dc bias the application note □How to choose Ferrite Components for EMI
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